

**Ministry of high Education and Scientific Research
Foundation of Technical Education
Technical Institute of kufa**

Power Electronics

**For Students of second class electrical department
By jaafer sadiq jaafer Lecturer
in electrical Dep.**

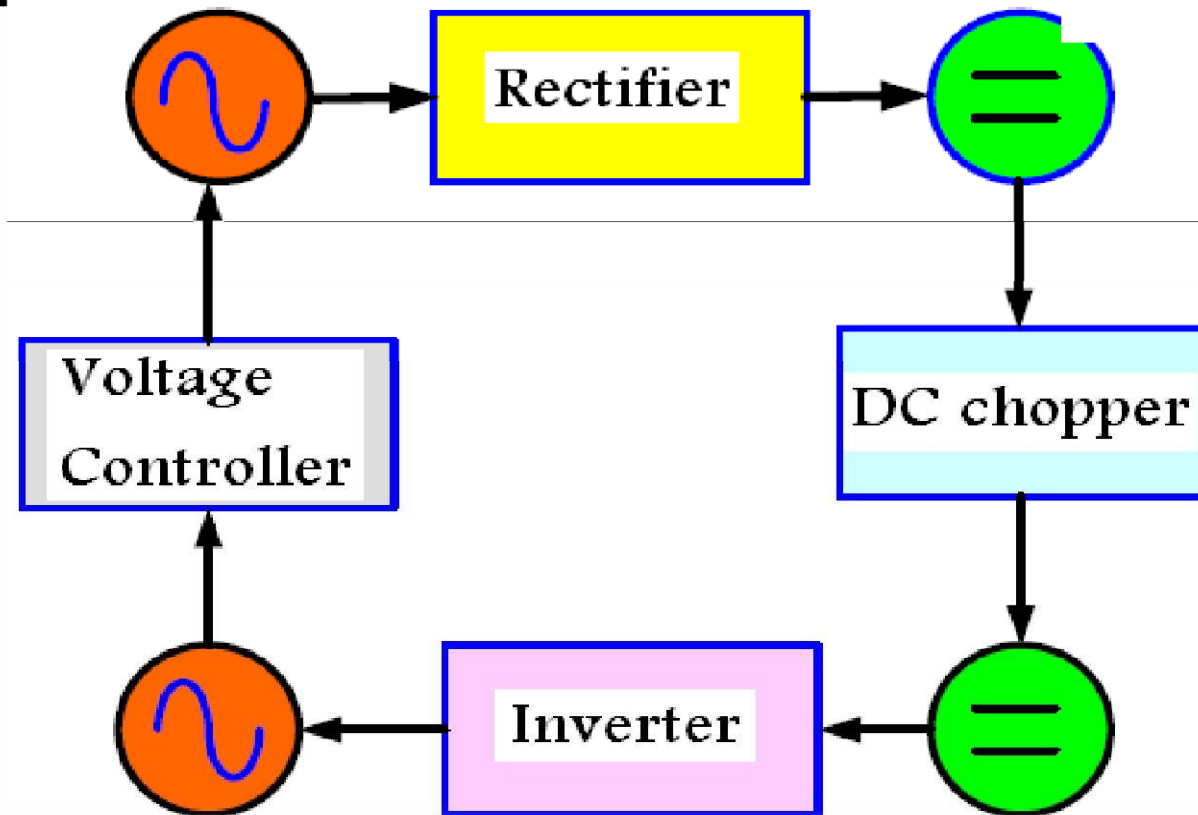
Week No -1

- **Power electronic**
- **Electronic components used in power electronics**
 - **Power Diode**
 - **Power transistor**
 - **Thyristor**
- **Prevision of single phase rectifier circuits by using diode**

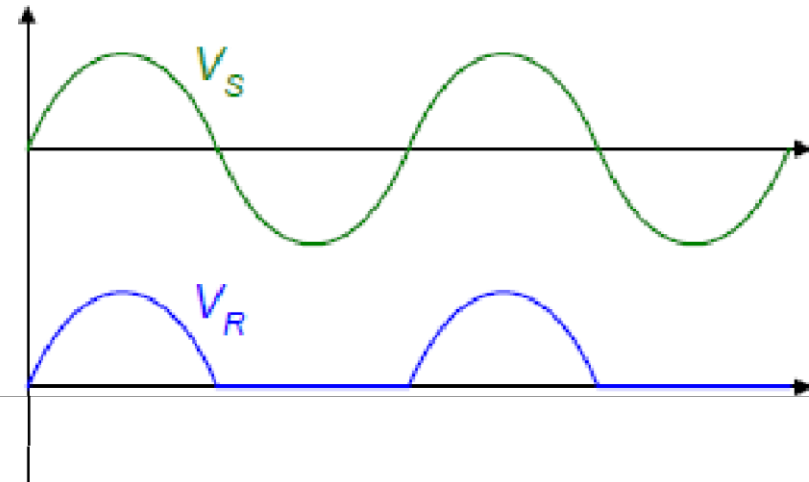
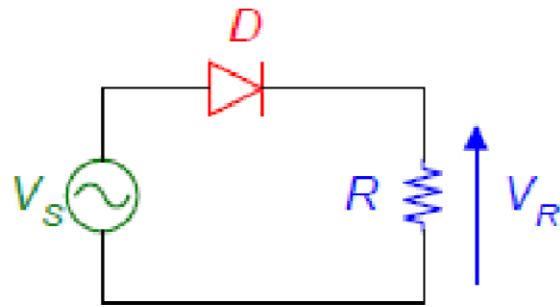
What is Power Electronics ?

- **Conversion of *Large Amounts of* Electric Power and Energy**
 - ac to dc
 - dc to ac
 - dc to dc
 - ac to ac

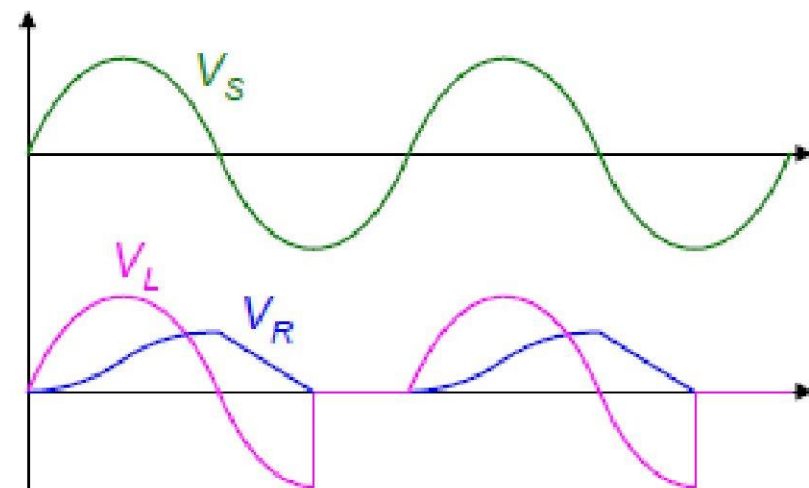
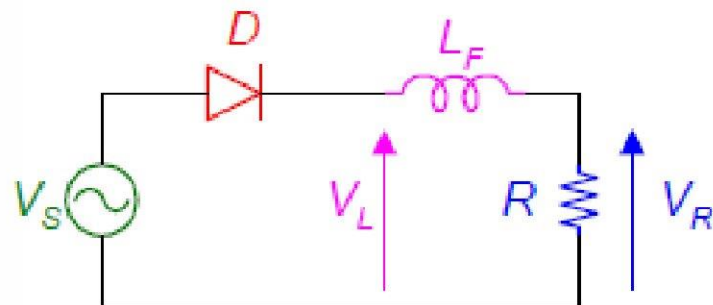
Diagram Block of Converters



Diode Rectifier



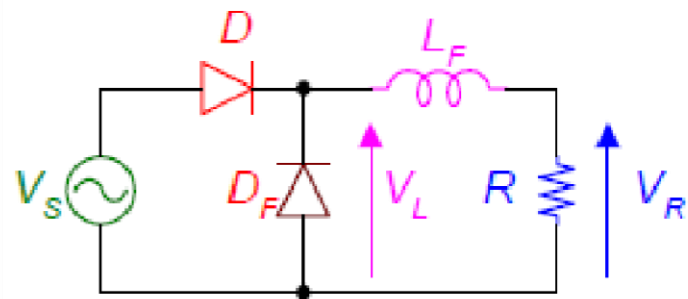
Half Bridge Rectifier



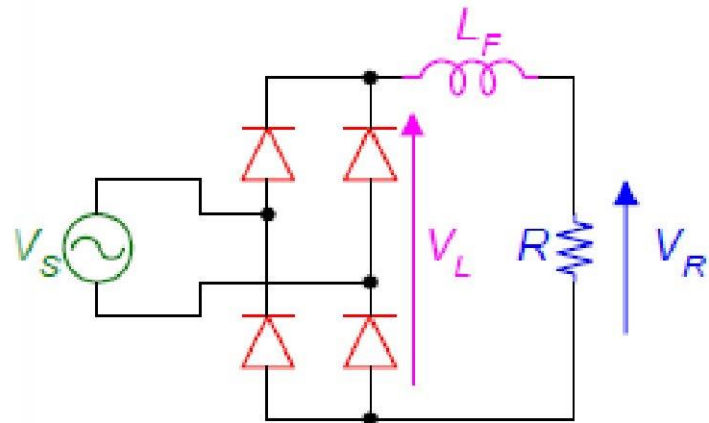
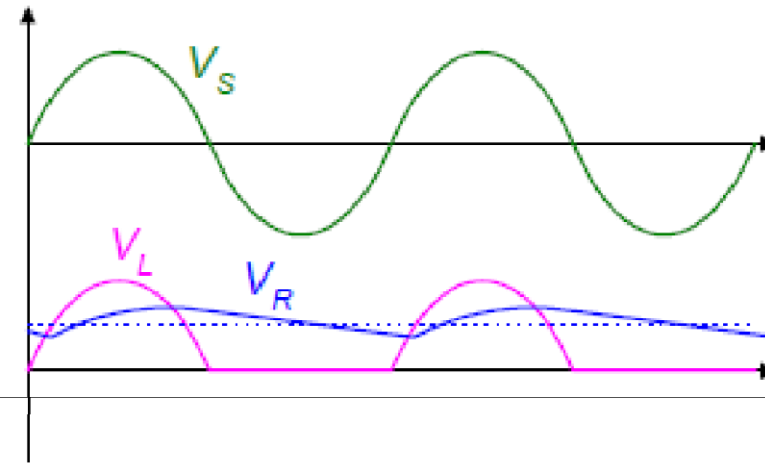
Half Bridge Rectifier with Smoothing Inductor



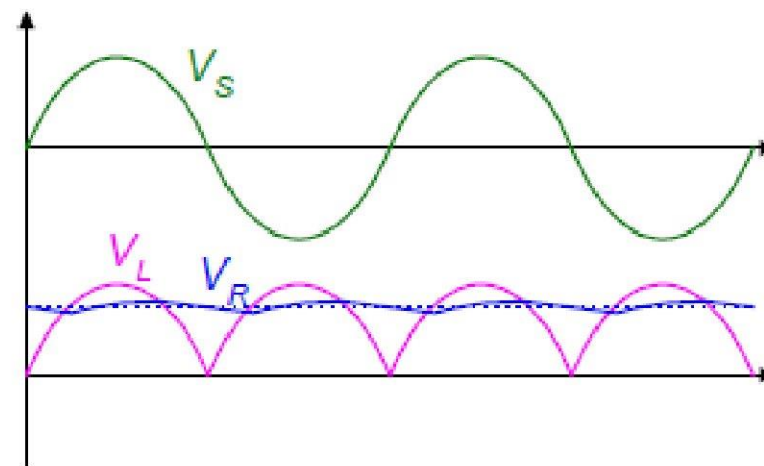
Diode Rectifier (Cnt'd)



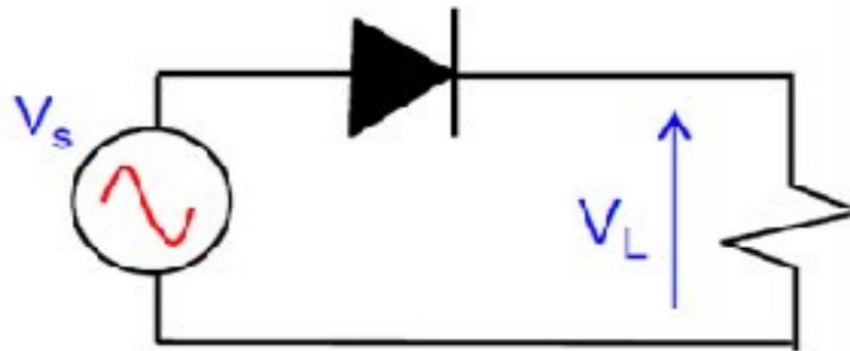
With Free-Wheeling Diode



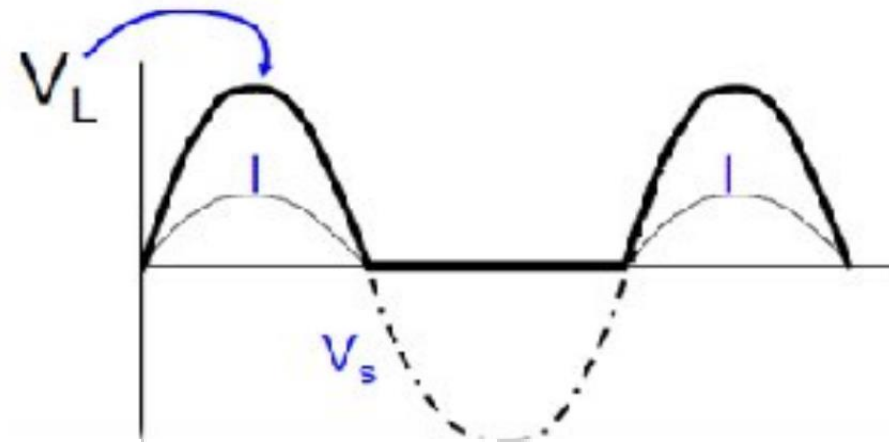
Full Bridge Rectifier



Single phase uncontrolled resistive load rectifier



(a) circuit diagram



(b) waveforms

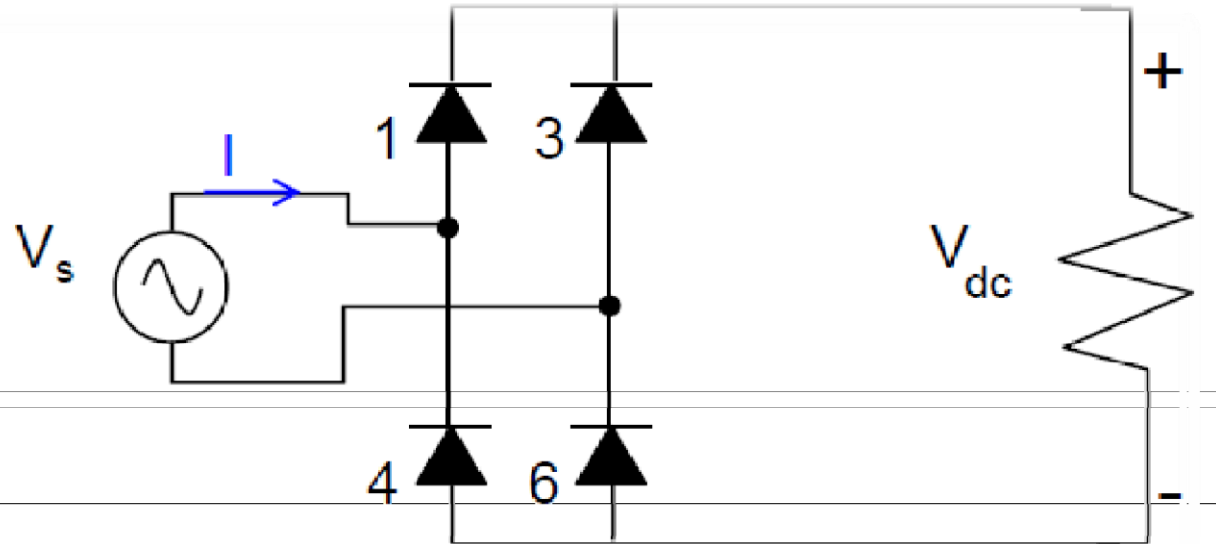
The main disadvantages of half wave rectifier are:

- 1- High ripple factor,
- 2- Low rectification efficiency,
- 3- Low transformer utilization factor, and,
- 4- DC saturation of transformer secondary winding.



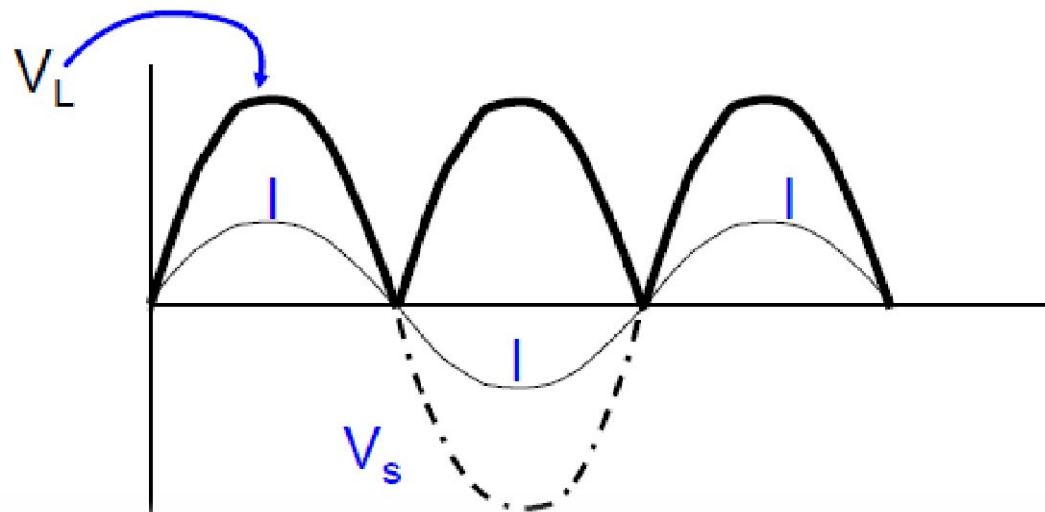
Single phase full wave uncontrolled resistive load rectifier

Full-wave diode
rectifier



Ripple of voltage
and current is

High



Performance Parameters

- Average value of the output voltage, V_{dc}
- Average value of the output current, I_{dc}
- Output dc power, P_{dc}
 - $P_{dc} = V_{dc} I_{dc}$
- rms value of the input voltage, V_{rms}
- Output ac power, P_{ac}
 - $P_{ac} = V_{rms} I_{rms}$



Performance Parameters (continued)

- Efficiency , η

$$\eta = P_{dc} / P_{ac}$$

- Effective (rms) value of the ac component of the output voltage, V_{ac}

$$V_{ac} = \sqrt{V_{rms}^2 - V_{dc}^2}$$

- Form factor, FF

$$FF = V_{rms} / V_{dc}$$

- Ripple factor, RF

$$RF = V_{ac} / V_{dc}$$



Performance Parameters

- Alternate form for ripple factor

$$RF = \sqrt{\left(\frac{V_{rms}}{V_{dc}}\right)^2 - 1} = \sqrt{FF^2 - 1}$$

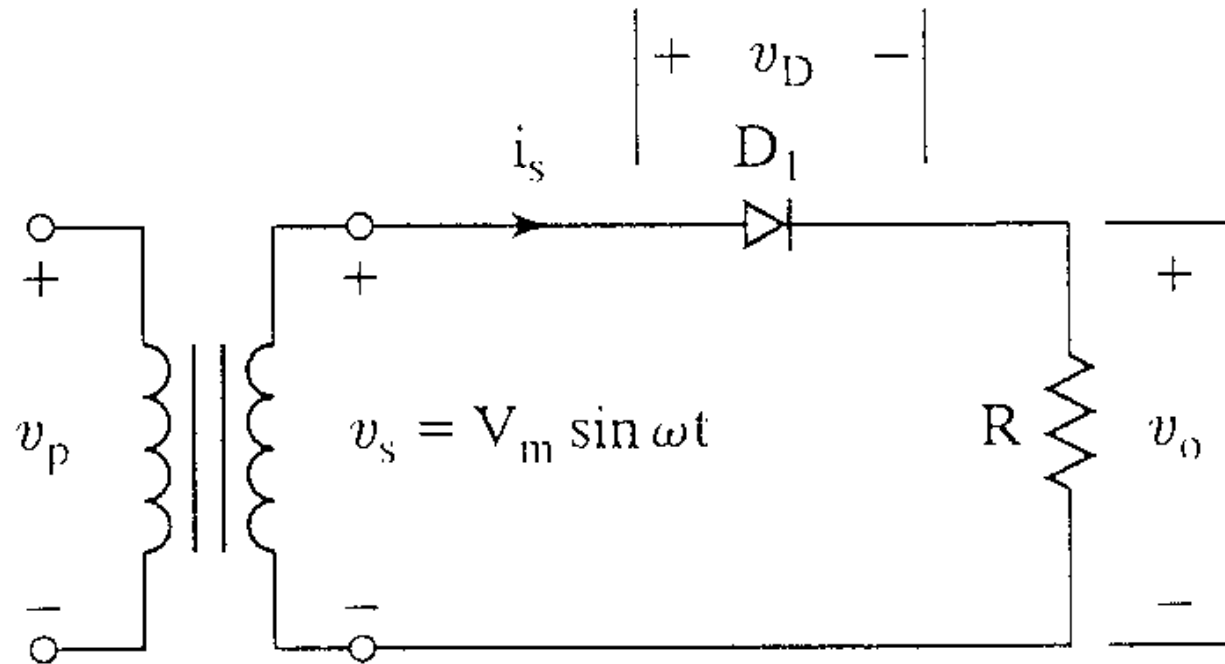
- Transformer utilization factor, TUF

$$TUF = P_{dc} / V_s I_s$$

V_s , I_s are rms voltage and current of the transformer secondary



- Determine η , FF, RF,TUF, PIV of the diode, when $V_s = 120 \sin \omega t$, $R_L = 12 \Omega$.

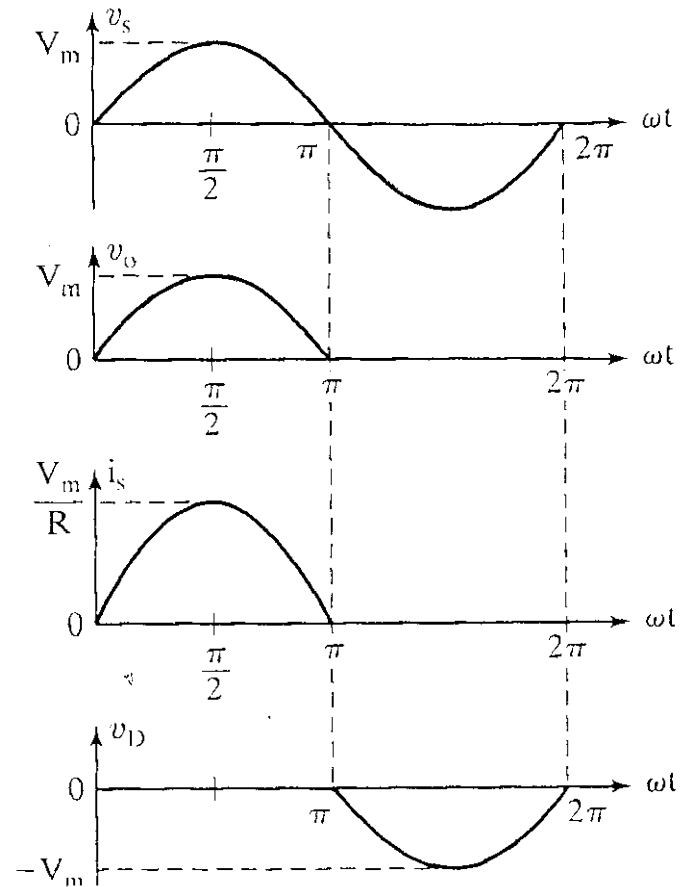


Determine the Average Voltage, V_{dc}

$$V_{dc} = \frac{1}{T} \int_0^T v_L(t) dt$$

$$V_{dc} = \frac{1}{T} \int_0^{\frac{T}{2}} V_m \sin \omega t dt$$

$$V_{dc} = -\frac{V_m}{\omega T} \left(\cos \frac{\omega T}{2} - 1 \right)$$



$$f = \frac{1}{T}$$

$$\omega = 2\pi f$$

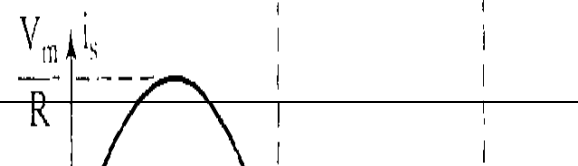
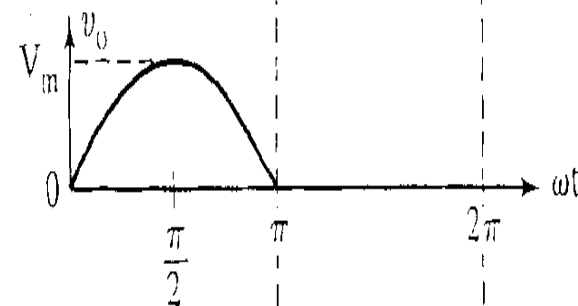
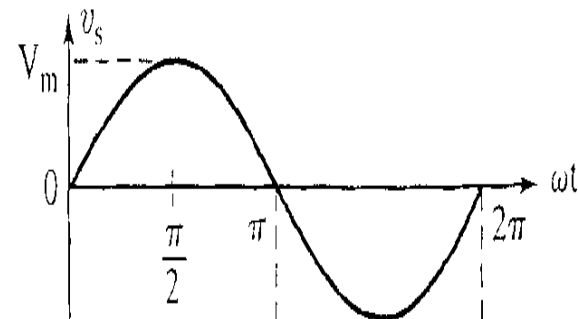
$$V_{\text{dc}} = \frac{V_{\text{m}}}{\pi} = 0.318 V_{\text{m}}$$

Determine the rms Voltage, V_{rms}

$$V_{\text{rms}} = \left[\frac{1}{T} \int_0^T v^2(t) dt \right]^{\frac{1}{2}}$$

$$V_{\text{rms}} = \left[\frac{1}{T} \int_0^T (V_m \sin \omega t)^2 dt \right]^{\frac{1}{2}}$$

$$V_{\text{rms}} = \frac{V_m}{\sqrt{2}} = 0.707 V_m$$



Determine P_{dc} , P_{ac} , and η

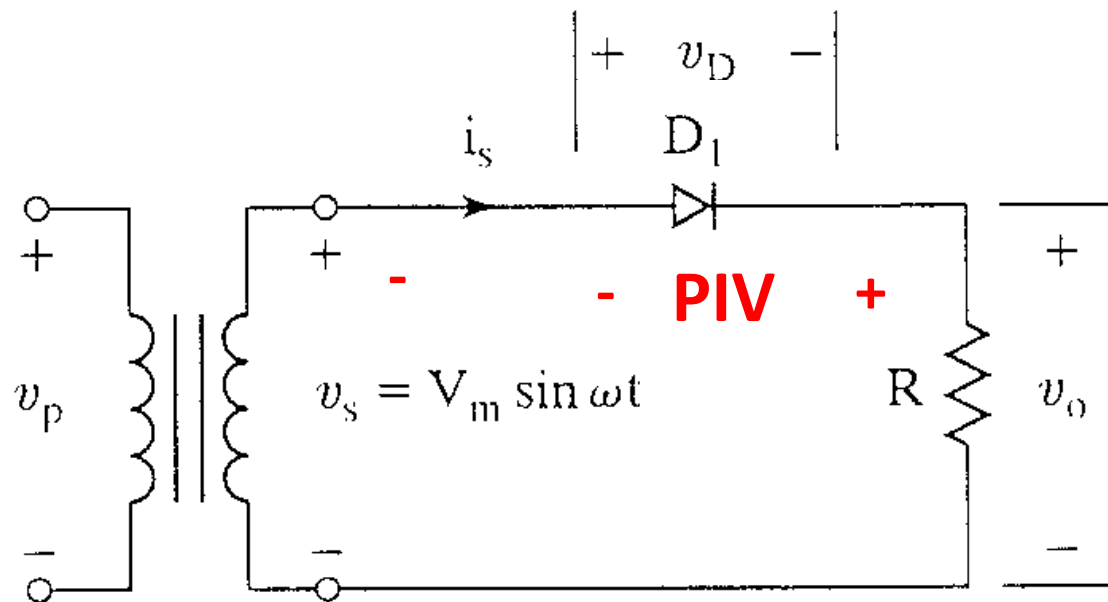
$$P_{dc} = \frac{(0.318V_m)^2}{R}$$

$$P_{ac} = \frac{(0.5V_m)^2}{R}$$

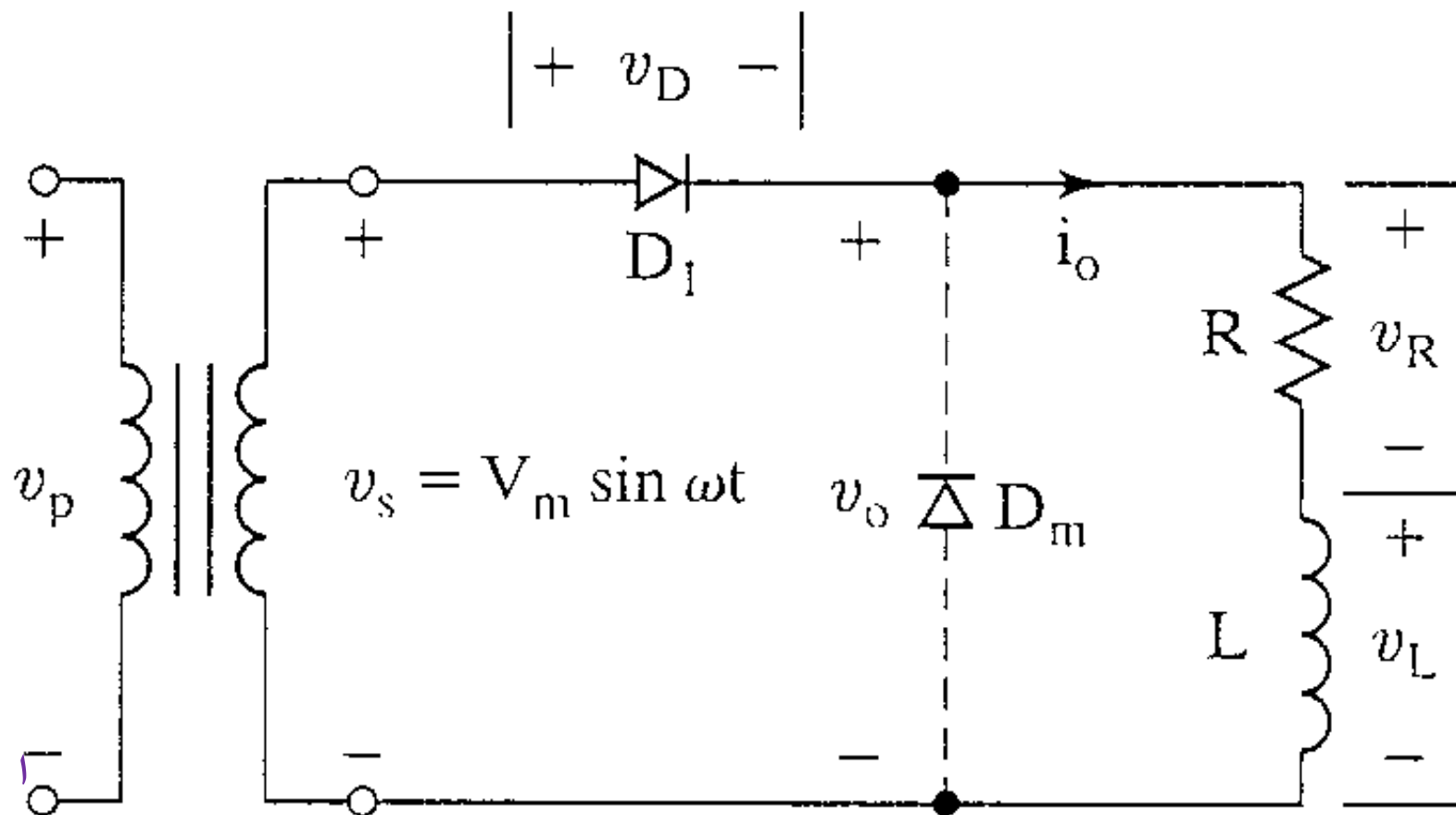
$$\eta = \frac{(0.318V_m)^2}{(0.5V_m)^2} = 40.5\%$$

Determine the PIV

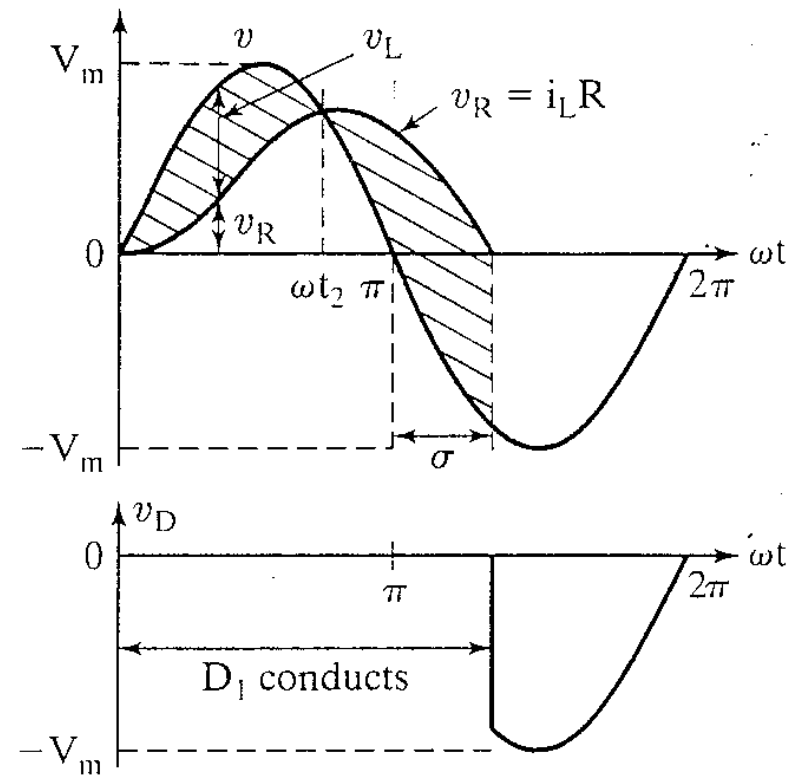
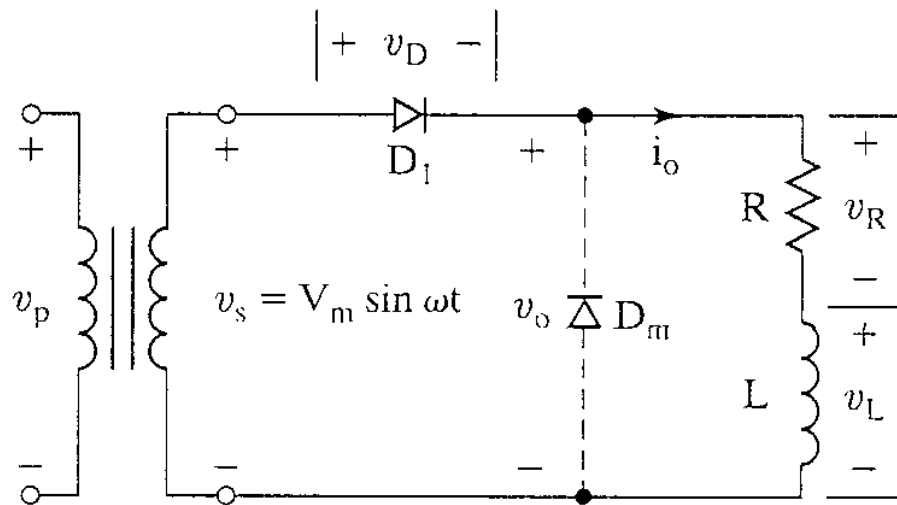
- PIV is the maximum (peak) voltage that appears across the diode when reverse biased. Here, $\text{PIV} = V_m$.



Half-Wave Rectifier with R-L Load



Waveforms of Current and Voltage



Conduction period of D_1 extends beyond $\omega t = \pi$



Average Output Voltage

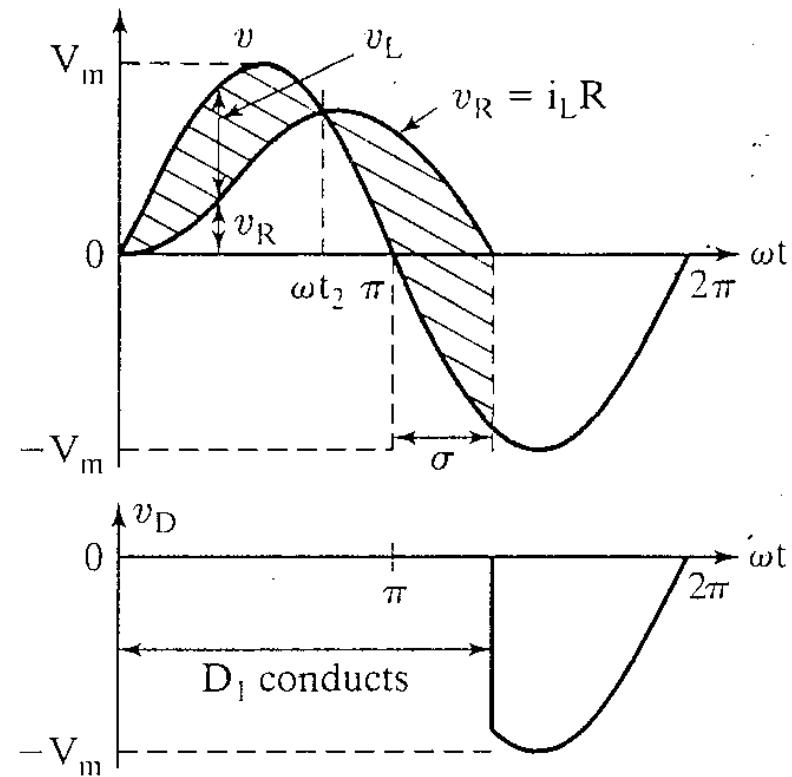
$$V_{dc} = \frac{V_m}{2\pi} \int_0^{\pi+\sigma} \sin \omega t d(\omega t)$$

$$V_{dc} = \frac{V_m}{2\pi} \left[-\cos \omega t \right]_0^{\pi+\sigma}$$

$$V_{dc} = \frac{V_m}{2\pi} \left[1 - \cos(\pi + \sigma) \right]$$

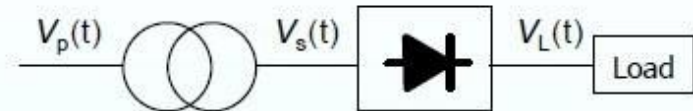
$$I_{dc} = \frac{V_{dc}}{R}$$

Increase average voltage and current by making $\sigma = 0$



Comparison among topologies 1-Ph.

- Secondary voltage is sinusoidal: $v_s(t) = V_s \sin(2\pi f_{\text{mains}} t)$
- Resistive Load
- Ideal devices (no device losses)



Parameter	Half-Wave	Full - Wave (Center-tapped)	Full - Wave (Bridge)
Rectified Voltage - V_{DC}	$V_s/\pi = 0.318 \cdot V_s$	$2 \cdot V_s/\pi = 0.636 \cdot V_s$	$2 \cdot V_s/\pi = 0.636 \cdot V_s$
rms Output Voltage - V_L	$V_s/2 = 0.318 \cdot V_s$	$V_s/\sqrt{2} = 0.707 \cdot V_s$	$V_s/\sqrt{2} = 0.707 \cdot V_s$
Form Factor - FF	1.57	1.11	1.11
Rectification Ratio - η	0.405	0.81	0.81
Ripple Factor - RF	1.21	0.482	0.482
Transformer Utilization Factor - TUF	0.286	0.572	0.81
Diode Peak Inverse Voltage (PIV) - V_{RRM}	$V_s = \pi \cdot V_{DC}$	$2 \cdot V_s = \pi \cdot V_{DC}$	$V_s = \pi/2 \cdot V_{DC}$
Peak Direct Voltage (PDV - thyristors only) - V_{DRM}	$V_s = \pi \cdot V_{DC}$	$2 \cdot V_s = \pi \cdot V_{DC}$	$V_s = \pi/2 \cdot V_{DC}$
Diode Peak Forward Current - I_{FRM}	$\pi \cdot I_{DC}$	$\pi/2 \cdot I_{DC}$	$\pi/2 \cdot I_{DC}$
Diode Average Current - $I_{F(AV)}$	I_{DC}	$0.5 \cdot I_{DC}$	$0.5 \cdot I_{DC}$
Diode Rms Current - $I_{F(RMS)}$	$\pi/2 \cdot I_{DC}$	$\pi/4 \cdot I_{DC}$	$\pi/4 \cdot I_{DC}$
Fundamental Ripple Frequency - f_R	f_{mains}	$2 \cdot f_{\text{mains}}$	$2 \cdot f_{\text{mains}}$

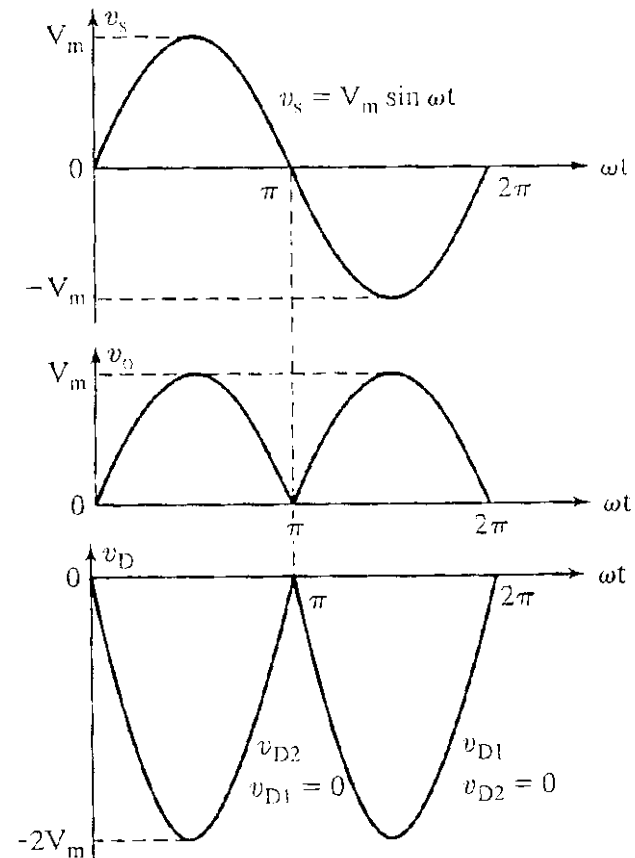


Waveforms for the Full-Wave Rectifier

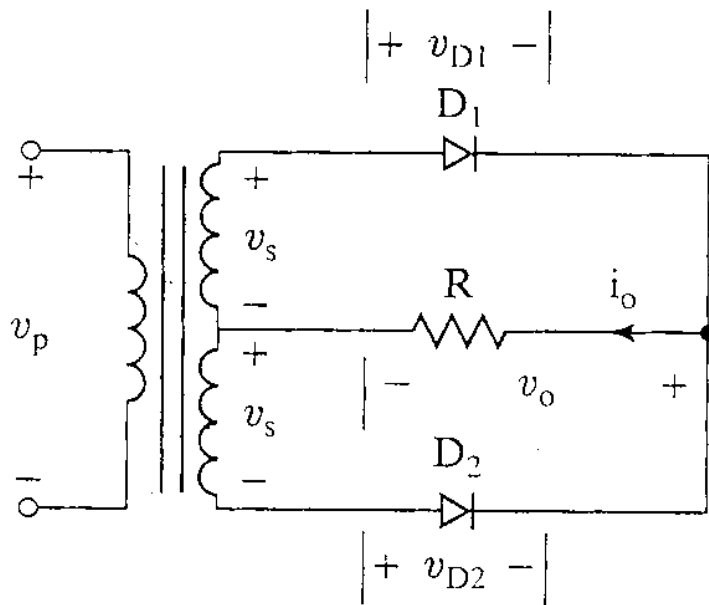
$$V_{dc} = \frac{2}{T} \int_0^{\frac{T}{2}} V_m \sin \omega t$$

$$V_{dc} = \frac{2V_m}{\pi}$$

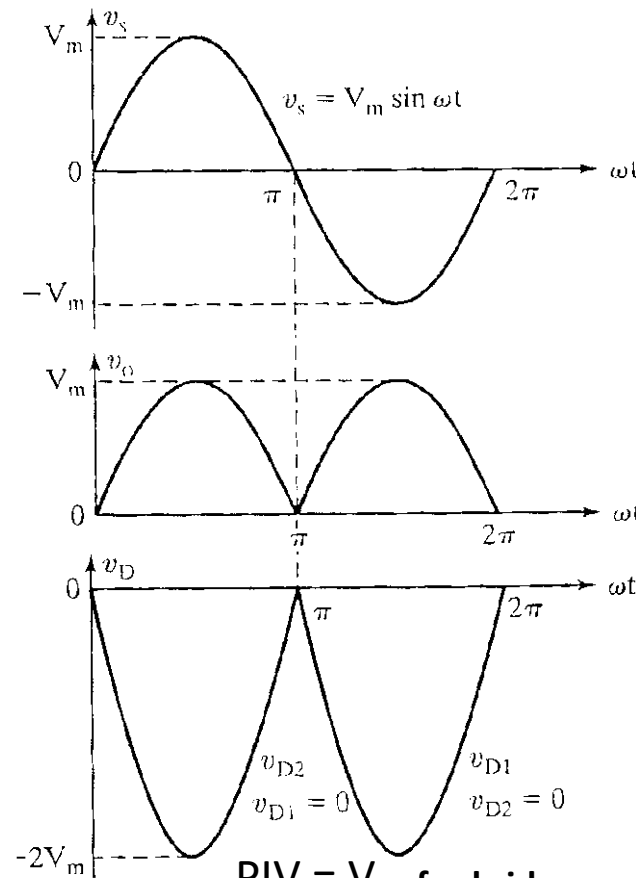
$$V_{dc} = 0.636V_m$$



Single-Phase Full-Wave Rectifier



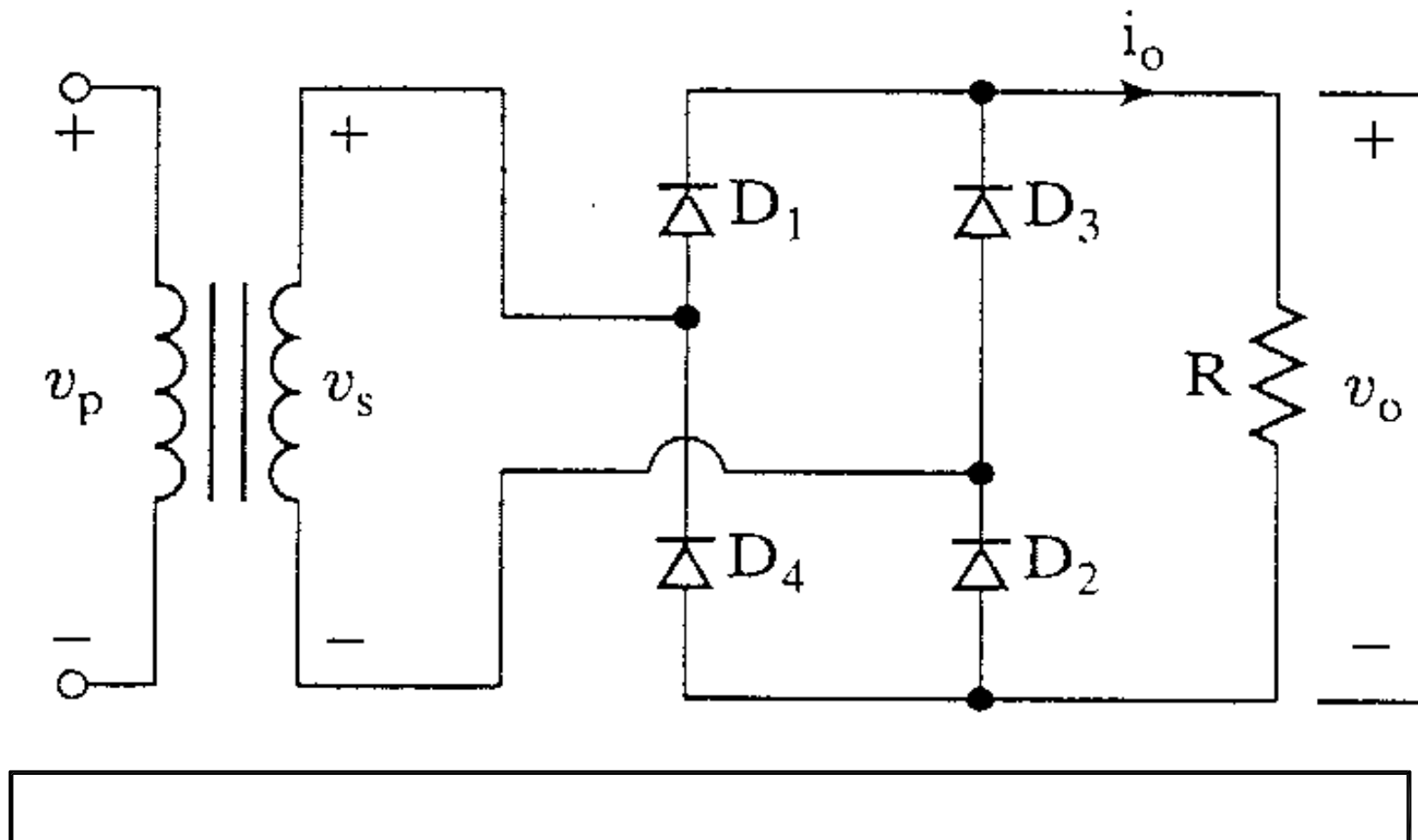
$PIV = 2V_m$,for centertap transformer



$PIV = V_m$ for bridge rectifier



Full-Wave Bridge Rectifier



Waveforms for the Full-Wave Bridge

